

# **High Voltage Fast-Switching NPN Power Transistor**

### **FJPF13007**

- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Mode Power Supply
- This is a Pb–Free Device

#### **MAXIMUM RATINGS** (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector–Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	8	Α
I <sub>CP</sub>	Collector Current (Pulse)	16	Α
I <sub>B</sub>	Base Current	4	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> = 25°C)	40	W
$T_J$	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65~150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **hFE CLASSIFICATION**

Classification	H1	H2
h <sub>FE1</sub>	15~28	26~39

## 797

- 1. Base
- 2. Collector
- 3. Emitter

TO-220 Fullpack, 3-Lead CASE 221AT

#### **MARKING DIAGRAM**

J13007 -x AYWWZZ

J13007- = Specific Device Code

 $\begin{array}{lll} x & = h_{FE} \mbox{ Grade} \\ A & = \mbox{Site Code} \\ Y & = \mbox{ Year} \\ WW & = \mbox{ Work Week} \\ ZZ & = \mbox{ Assembly Lot Code} \\ \end{array}$ 

#### **ORDERING INFORMATION**

Device	Package	Shipping		
FJPF13007H2TU	TO-220 Fullpack	1000 Units / Tube		

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV <sub>CEO</sub>	Collector–Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	400	-	_	V
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9 \text{ V, } I_{C} = 0$	-	-	1	μΑ
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 2 A V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 A	8 5		60 30	
V <sub>CE(sat)</sub>	Collector–Emitter Saturation Voltage	I <sub>C</sub> = 2 A, I <sub>B</sub> = 0.4 A I <sub>C</sub> = 5 A, I <sub>B</sub> = 1 A I <sub>C</sub> = 8 A, I <sub>B</sub> = 2 A	- - -	- - -	1.0 2.0 3.0	V V V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2 A, I <sub>B</sub> = 0.4 A I <sub>C</sub> = 5 A, I <sub>B</sub> = 1 A	_ _		1.2 1.6	V V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 0.5 A	4	-	_	MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, f = 0.1 MHz	-	110	-	pF
t <sub>ON</sub>	Turn On Time	$V_{CC} = 125 \text{ V}, I_C = 5 \text{ A}, I_{B1} = -I_{B2} = 1 \text{ A},$	-	-	1.6	μS
t <sub>STG</sub>	Storage Time	$R_L = 25 \Omega$	_	-	3.0	μS
t <sub>F</sub>	Fall Time		_	-	0.7	μS

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*Pulse Test:  $PW \le 300 \ \mu s$ , Duty Cycle  $\le 2\%$ 

#### **FJPF13007**

#### **TYPICAL CHARACTERISTICS**

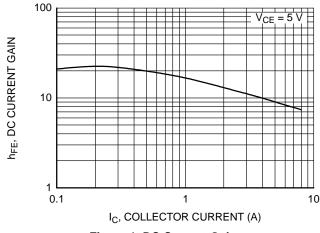


Figure 1. DC Current Gain

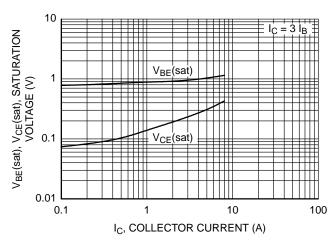
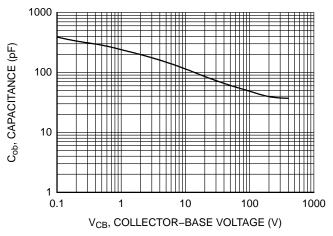


Figure 2. Saturation Voltage



**Figure 3. Collector Output Capacitance** 

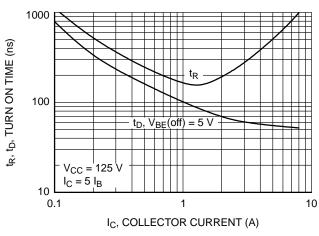


Figure 4. Turn On Time

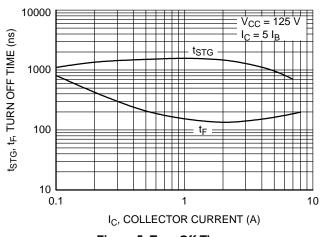


Figure 5. Turn Off Time

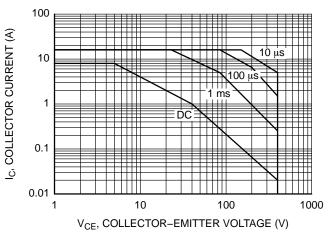


Figure 6. Forward Biased Safe Operating Area

#### FJPF13007

#### TYPICAL CHARACTERISTICS (CONTINUED)

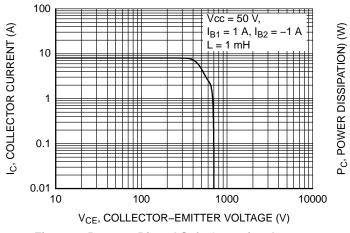


Figure 7. Reverse Biased Safe Operating Area

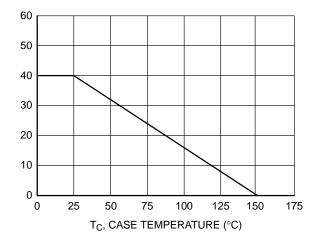
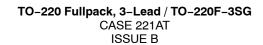
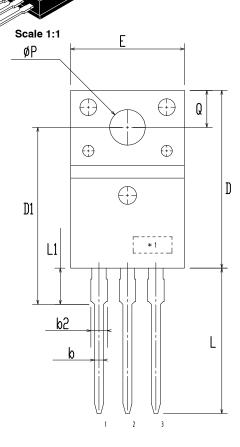


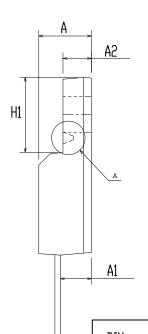
Figure 8. Power Derating

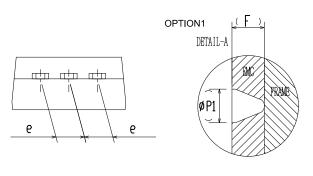




**DATE 19 JAN 2021** 







DIM	HILLIHITEKS		
ויונע	MIN	NDM	MAX
Α	4.50	4.70	4.90
A1	2.56	2.76	2.96
A2	2.34	2.54	2.74
b	0.70	0.80	0.90
b2	~	2	1.47
С	0.45	0.50	0.60
D	15.67	15.87	16.07
D1	15.60	15.80	16.00
E	9.96	10.16	10.36
е	2.34	2.54	2.74
F	~	0.84	2
H1	6.48	6.68	6.88
L	12.78	12.98	13.18
L1	3.03	3.23	3.43
ØΡ	2.98	3.18	3.38
Ø P1	~	1.00	~
Q	3.20	3.30	3.40

MILL IMITERS

#### NOTES:

- A. DIMENSION AND TOLERANCE AS ASME Y14.5-2009
- B. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUCSIONS.

C

C. OPTION 1 - WITH SUPPORT PIN HOLE OPTION 2 - NO SUPPORT PIN HOLE

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DESCRIPTION:	I: TO-220 FULLPACK, 3-LEAD / TO-220F-3SG		PAGE 1 OF 1	

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